



A Product Line of Diodes Incorporated



50V NPN SURFACE MOUNT TRANSISTOR IN SOT89

Features

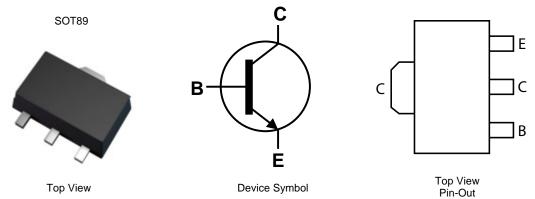
- BV_{CEO} > 50V
- I_C = 3A High Continuous Current
- Low saturation voltage V_{CE(sat)} < 350mV @ 1A
- Complementary PNP type: 2DA1797
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.052 grams (Approximate)

Applications

- Load Management Functions
- Solenoid, Relay and Actuator Drivers
- DC DC Modules



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
2DC4672-13	4672	13	12	2,500
2DC4672-13R	4672	13	12	4,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

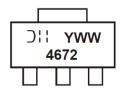
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html

Marking Information

Notes:



4672 = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 8 = 2008) WW = Week code 01 - 53





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	3	A
Peak Pulse Current	I _{CM}	6	A
Base Current	IB	500	mA

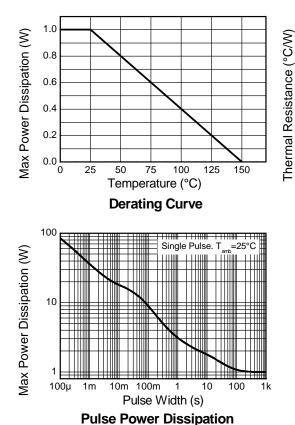
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

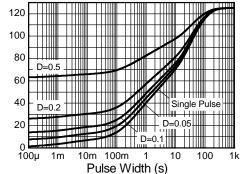
Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	P	1	w	
	(Note 6)	PD	2	V	
Thermal Desistance Innetion to Ambient Air	(Note 5)	D	125	°C/W	
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _{θJA}	62.5		
Thermal Resistance, Junction to Leads	(Note 7)	R _{0JL}	5.73	°C/W	
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

Notes: 5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition. 6. Same as note (5), except the device is mounted on 40mm x 40mm x 1.6mm FR4 PCB

7. Thermal resistance from junction to solder-point (on the exposed collector pad).

Thermal Characteristics and Derating Information





Transient Thermal Impedance



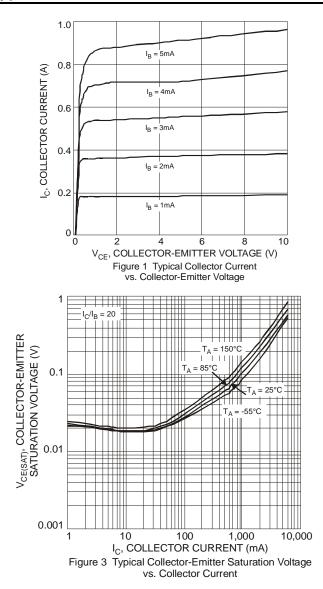


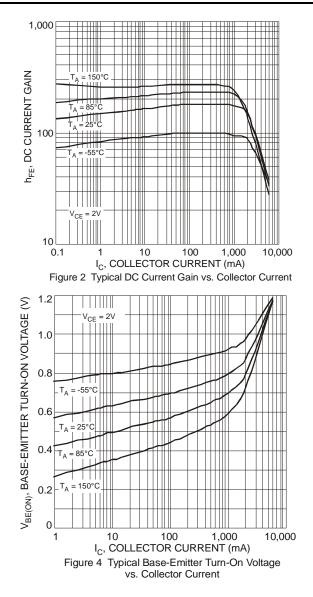
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV CBO	60	_	—	V	I _C = 100μΑ
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	50	—	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BVEBO	7	—	_	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	—	—	100	nA	$V_{CB} = 60V$
Emitter Cutoff Current	I _{EBO}	—	—	100	nA	V _{EB} = 5.6V
DC Current Transfer Static Ratio (Note 8)	h _{FE}	82 45	-	270 —	_	$I_{C} = 500 \text{mA}, V_{CE} = 2 \text{V}$ $I_{C} = 1.5 \text{A}, V_{CE} = 2 \text{V}$
Collector-Emitter Saturation Voltage (Note 8)	V _{CE(sat)}	_	105	350	mV	$I_{\rm C} = 1$ A, $I_{\rm B} = 50$ mA
Transitional Frequency	f⊤	_	180	_	MHz	$I_C = 100$ mA, $V_{CE} = 2V$ f = 1MHz
Output Capacitance	Cobo		17	_	pF	$V_{CB} = 10V, f = 1MHz,$

Note: 8. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

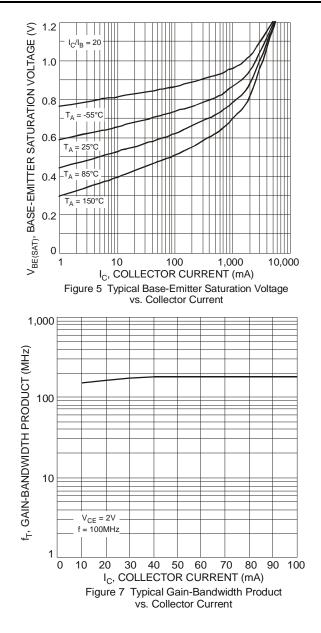


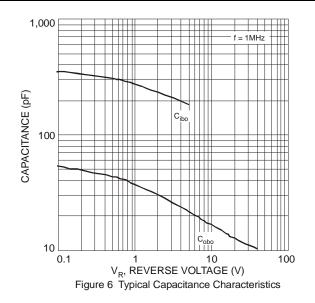






Typical Electrical Characteristics (cont.)



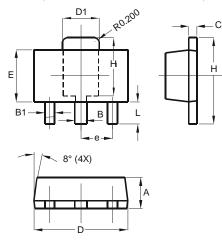






Package Outline Dimensions

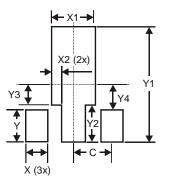
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT89				
Dim	Min	Max			
Α	1.40	1.60			
В	0.44	0.62			
B1	0.35	0.54			
С	0.35	0.44			
D	4.40	4.60			
D1	1.62	1.83			
E	2.29	2.60			
е	1.50 Typ				
Н	3.94	4.25			
H1	2.63	2.93			
L	0.89	1.20			
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500





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